# DATA SHEET



# MOS FIELD EFFECT TRANSISTOR μ**ΡΑ1853**

## P-CHANNEL MOS FIELD EFFECT TRANSISTOR FOR SWITCHING

#### DESCRIPTION

The  $\mu$ PA1853 is a switching device which can be driven directly by a 4-V power source.

The µPA1853 features a low on-state resistance and excellent switching characteristics, and is suitable for applications such as power switch of portable machine and so on.

#### FEATURES

- Can be driven by a 4-V power source
- · Low on-state resistance  $R_{DS(on)1} = 85 \text{ m}\Omega \text{ MAX.} (V_{GS} = -10 \text{ V}, \text{ ID} = -1.5 \text{ A})$ 
  - $R_{DS(on)2} = 152 \text{ m}\Omega \text{ MAX.}$  (Vgs = -4.5 V, ID = -1.5 A)
- $R_{DS(on)3} = 180 \text{ m}\Omega \text{ MAX.}$  (Vgs = -4.0 V, Ip = -1.5 A)

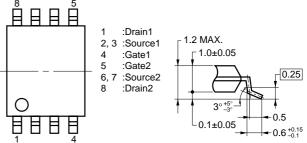
#### **ORDERING INFORMATION**

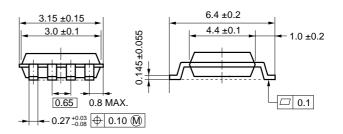
PART NUMBER	PACKAGE
μPA1853GR-9JG	Power TSSOP8

#### ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

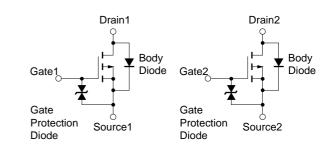
Drain to Source Voltage	Vdss -30	
Gate to Source Voltage	Vgss	-20/+5
Drain Current (DC)	ID(DC)	<del>+</del> 2.5
Drain Current (pulse) Note1	D(pulse)	<b>∓</b> 10
Total Power Dissipation Note2	Рт	2.0
Channel Temperature	Tch	150
Storage Temperature	Tstg	–55 to +150

PACKAGE DRAWING (Unit : mm)





#### EQUIVALENT CIRCUIT



**Notes 1.** PW  $\leq$  10  $\mu$ s, Duty Cycle  $\leq$  1 %

2. Mounted on ceramic substrate of 5000 mm<sup>2</sup> x 1.1 mm

Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

V V

A Α

Ŵ °C

°С

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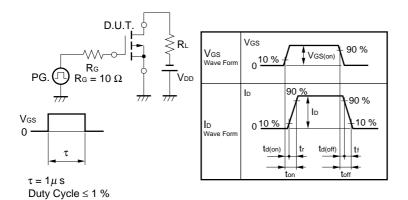
The mark  $\star$  shows major revised points.

### \* ELECTRICAL CHARACTERISTICS (TA = 25 °C)

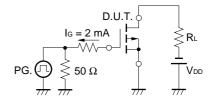
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CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Drain Cut-off Current	IDSS	$V_{DS} = -30 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$			-10	μA
Gate Leakage Current	lgss	$V_{GS} = \mp 20 \text{ V}, \text{ Vds} = 0 \text{ V}$			<b>∓ 10</b>	μA
Gate Cut-off Voltage	V <sub>GS(off)</sub>	$V_{DS} = -10 V$ , $I_{D} = -1 mA$	-1.0	-1.7	-2.5	V
Forward Transfer Admittance	yfs	$V_{DS} = -10 V$ , $I_D = -1.5 A$	1	3.6		S
Drain to Source On-state Resistance	RDS(on)1	$V_{GS} = -10 \text{ V}, \text{ ID} = -1.5 \text{ A}$		64	85	mΩ
	RDS(on)2	$V_{GS} = -4.5 V$ , $I_D = -1.5 A$		114	152	mΩ
	RDS(on)3	$V_{GS} = -4.0 \text{ V}, \text{ Id} = -1.5 \text{ A}$		135	180	mΩ
Input Capacitance	Ciss	$V_{DS} = -10 V$		520		pF
Output Capacitance	Coss	Vgs = 0 V		200		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		82		pF
Turn-on Delay Time	td(on)	$V_{DD} = -10 V$		60		ns
Rise Time	tr	ID = -1.5 A		220		ns
Turn-off Delay Time	td(off)	$V_{GS(on)} = -10 V$		800		ns
Fall Time	tr	Rg = 10 Ω		620		ns
Total Gate Charge	QG	$V_{DD} = -24 V$		12		nC
Gate to Source Charge	QGS	I⊳ = −2.5 A		2		nC
Gate to Drain Charge	Qgd	Vgs = -10 V		3		nC
Diode Forward Voltage	VF(S-D)	IF = 2.5 A, VGS = 0 V		0.73		V

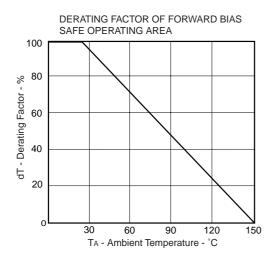
#### **TEST CIRCUIT 1 SWITCHING TIME**

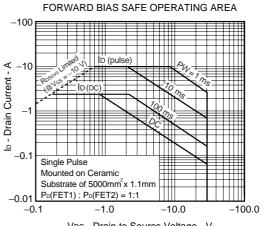


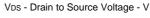
### TEST CIRCUIT 2 GATE CHARGE



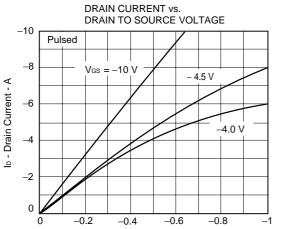
#### TYPICAL CHARACTERISTICS (T<sub>A</sub> = 25°C)



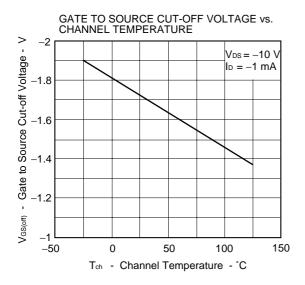




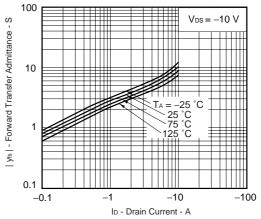
TRANSFER CHARACTERISTICS



V<sub>DS</sub> - Drain to Source Voltage - V

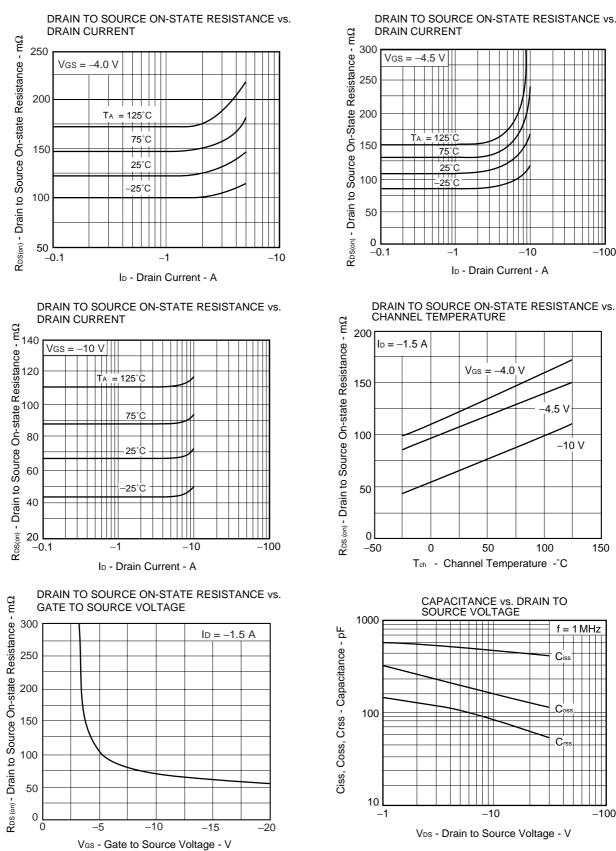


FORWARD TRANSFER ADMMITTANCE vs. DRAIN CURRENT



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-100



DRAIN TO SOURCE ON-STATE RESISTANCE vs.

-10

4.5 V

100

-10 V

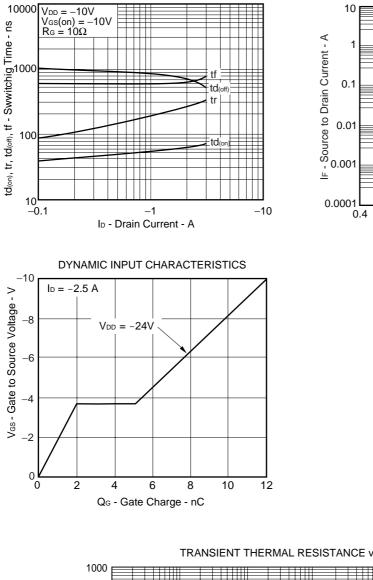
150

-100

f = 1 MHz

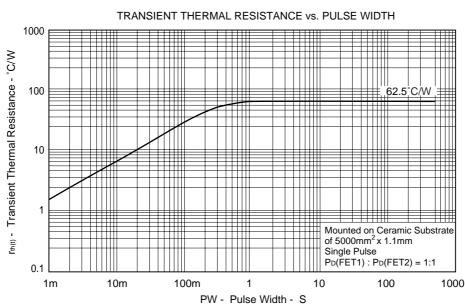
Ciss

.Crs

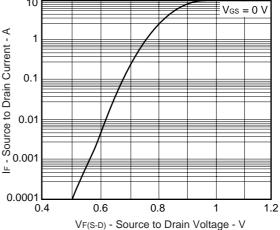


SWITCHING CHARACTERISTICS

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SOURCE TO DRAIN DIODE FORWARD VOLTAGE



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